Quad D-type flip-flop with reset; positive-edge triggerRev. 5 — 29 January 2016Product of

Product data sheet

General description 1.

The 74HC175; 74HCT175 is a quad positive-edge triggered D-type flip-flop with individual data inputs (Dn) and complementary outputs (Qn and Qn). The common clock (CP) and master reset (MR) inputs load and reset all flip-flops simultaneously. The D-input that meets the set-up and hold time requirements on the LOW-to-HIGH clock transition will be stored in the flip-flop and appear at the Q output. A LOW on MR causes the flip-flops and outputs to be reset LOW. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

Features and benefits 2.

- Input levels:
 - For 74HC175: CMOS level
 - For 74HCT175: TTL level
- Four edge-triggered D-type flip-flops
- Asynchronous master reset
- Complies with JEDEC standard no. 7A
- ESD protection:
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V.
- Multiple package options
- Specified from –40 °C to +85 °C and –40 °C to +125 °C.

Ordering information 3.

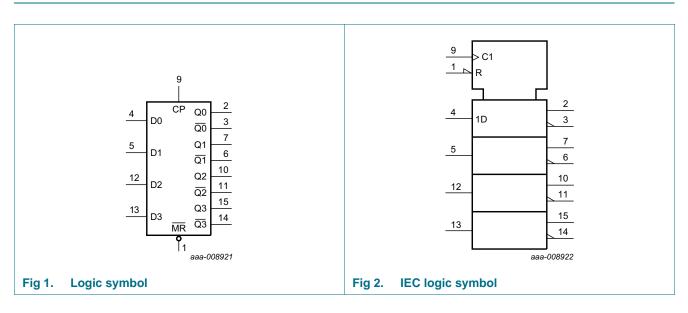
Table 1. **Ordering information**

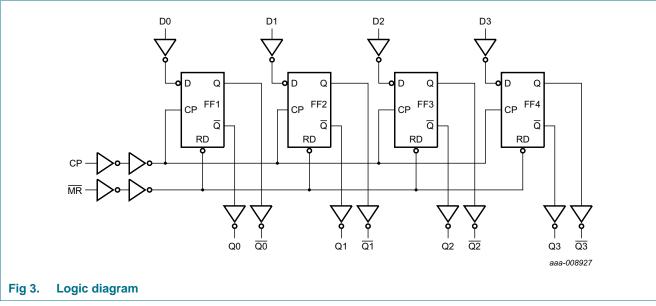
Type number	Package								
	Temperature range	Name	Description	Version					
74HC175D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width	SOT109-1					
74HCT175D	_		3.9 mm						
74HC175DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads;	SOT338-1					
74HCT175DB	_		body width 5.3 mm						
74HC175PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1					
74HCT175PW	_		body width 4.4 mm						



Quad D-type flip-flop with reset; positive-edge trigger

4. Functional diagram

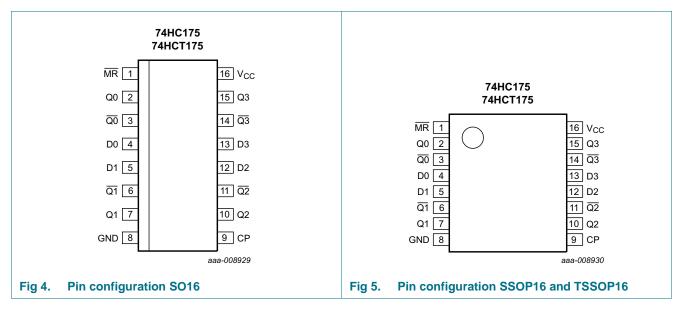




Quad D-type flip-flop with reset; positive-edge trigger

5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
MR	1	asynchronous master reset input (active LOW)
Q0 to Q3	2, 7, 10, 15	flip-flop output
Q0 to Q3	3, 6, 11, 14	complementary flip-flop output
D0 to D3	4, 5, 12, 13	data input
GND	8	ground (0 V)
СР	9	clock input (LOW-to-HIGH edge-triggered)
V _{CC}	16	positive supply voltage

6. Functional description

Table 3.Function table

Operating modes	Inputs			Outputs	
	MR	СР	Dn	Qn	Qn
reset (clear)	L	Х	Х	L	Н
load "1"	Н	↑	h	Н	L
load "0"	Н	↑	I	L	Н

[1] H = HIGH voltage level;

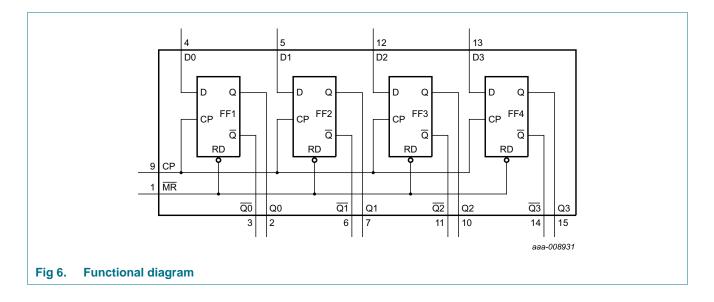
h = HIGH voltage level one set-up time prior to the LOW-to-HIGH clock transition;

L = LOW voltage level;

I = LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition;

X = don't care;

 \uparrow = LOW-to-HIGH clock transition.



7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+7	V
I _{IK}	input clamping current	$V_{I} < -0.5 V \text{ or } V_{I} > V_{CC} + 0.5 V$		-	±20	mA
I _{OK}	output clamping current	V_{O} < -0.5 V or V_{O} > V_{CC} + 0.5 V		-	±20	mA
lo	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$		-	±25	mA
I _{CC}	supply current			-	50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to +125 \ ^{\circ}C$				
		SO16, SSOP16 and TSSOP16	[1]	-	500	mW

For SO16 package: above 70 °C the value of P_{tot} derates linearly with 8 mW/K.
 For SSOP16 and TSSOP16 packages: above 60 °C the value of P_{tot} derates linearly with 5.5 mW/K.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions		74HC175			74HCT175		
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V _{CC}	0	-	V _{CC}	V
Vo	output voltage		0	-	V _{CC}	0	-	V _{CC}	V
T _{amb}	ambient temperature		-40	-	+125	-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 2.0 V$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 V$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	-	-	-	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	-40 °C te	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC17	5									
VIH	HIGH-level	V _{CC} = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V _{CC} = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V _{IL}	LOW-level	V _{CC} = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V _{CC} = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V _{CC} = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
V _{OH}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_{O} = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 4.5 \ V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -20 \ \mu A; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	5.9	-	5.9	-	V
		I_{O} = -4.0 mA; V_{CC} = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I_{O} = -5.2 mA; V_{CC} = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}$								
	output voltage	$I_0 = 20 \ \mu\text{A}; \ V_{CC} = 2.0 \ \text{V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 20 \ \mu A; V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_0 = 20 \ \mu A; V_{CC} = 6.0 \ V$	-	0	0.1	-	0.1	-	0.1	V
		I_{O} = 4.0 mA; V_{CC} = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
I	input leakage current	$V_1 = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±0.1	-	±1	-	±1	μA
I _{CC}	supply current	$V_1 = V_{CC}$ or GND; $I_0 = 0$ A; $V_{CC} = 6.0$ V	-	-	8.0	-	80	-	160	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT1	75					I	1		1	4
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V _{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V _{он}	HIGH-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
	output voltage	I _O = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I _O = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V _{OL}	LOW-level	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								1
	output voltage	$I_{O} = 20 \ \mu A; V_{CC} = 4.5 \ V$	-	0	0.1	-	0.1	-	0.1	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 5.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
II	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±0.1	-	±1	-	±1	μA

Table 6. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to	• +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
I _{CC}	supply current		-	-	8.0	-	80	-	160	μA
ΔI _{CC}	additional supply current	per input pin; $V_I = V_{CC} - 2.1 V$; other inputs at V_{CC} or GND; $V_{CC} = 4.5 V$ to 5.5 V								
		Dn input	-	40	144	-	180	-	196	μA
		CP input	-	60	216	-	270	-	294	μA
		MR input	-	100	360	-	450	-	490	μA
CI	input capacitance		-	3.5	-	-	-	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

GND (ground = 0 V); C_L = 50 pF unless otherwise specified; for test circuit, see Figure 10

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC17	5									
t _{pd}	propagation delay	CP to Qn, Qn; [1] see Figure 7								
		V _{CC} = 2.0 V	-	55	175	-	220	-	265	ns
		V _{CC} = 4.5 V	-	20	35	-	44	-	53	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	17	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	16	30	-	37	-	45	ns
t _{PHL}	HIGH to LOW propagation	MR to Qn, Qn; see Figure 9								
	delay	V _{CC} = 2.0 V	-	50	150	-	190	-	225	ns
		V _{CC} = 4.5 V	-	18	30	-	38	-	45	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	15	-	-	-	-	-	ns
		V _{CC} = 6.0 V	-	14	26	-	33	-	38	ns
t _t	transition time	Qn output; see Figure 7 [2]								
		V _{CC} = 2.0 V	-	19	75	-	95	-	110	ns
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
		V _{CC} = 6.0 V	-	6	13	-	16	-	19	ns

Quad D-type flip-flop with reset; positive-edge trigger

Table 7. Dynamic characteristics ...continued

GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; for test circuit, see Figure 10

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
t _W	pulse width	CP input HIGH or LOW; see Figure 7								
		V _{CC} = 2.0 V	80	22	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	8	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	6	-	17	-	20	-	ns
		MR input LOW; see <u>Figure 9</u>								
		V _{CC} = 2.0 V	80	19	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	7	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	6	-	17	-	20	-	ns
t _{rec}	recovery time	MR to CP; see Figure 9								
		V _{CC} = 2.0 V	5	-33	-	5	-	5	-	ns
		V _{CC} = 4.5 V	5	-12	-	5	-	5	-	ns
		V _{CC} = 6.0 V	5	-10	-	5	-	5	-	ns
t _{su}	set-up time	Dn to CP; see Figure 7								
		V _{CC} = 2.0 V	80	3	-	100	-	120	-	ns
		V _{CC} = 4.5 V	16	1	-	20	-	24	-	ns
		V _{CC} = 6.0 V	14	1	-	17	-	20	-	ns
t _h	hold time	Dn to CP; see Figure 7								
		V _{CC} = 2.0 V	25	2	-	30	-	40	-	ns
		V _{CC} = 4.5 V	5	0	-	6	-	8	-	ns
		V _{CC} = 6.0 V	4	0	-	5	-	7	-	ns
f _{max}	maximum	CP input; see Figure 7								
	frequency	V _{CC} = 2.0 V	6	25	-	4.8	-	4	-	MHz
		V _{CC} = 4.5 V	30	75	-	24	-	20	-	MHz
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	83	-	-	-	-	-	MHz
		V _{CC} = 6.0 V	35	89	-	28	-	24	-	MHz
C _{PD}	power dissipation capacitance	per package; [3] $V_1 = GND$ to V_{CC}	-	32	-	-	-	-	-	pF

Quad D-type flip-flop with reset; positive-edge trigger

Table 7. Dynamic characteristics ...continued

GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; for test circuit, see Figure 10

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	–40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HCT17	75				1		1	1		
t _{pd}	propagation		[1]							
	delay	see Figure 7								
		$V_{CC} = 4.5 V$	-	19	33	-	41	-	50	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	16	-	-	-	-	-	ns
t _{PHL}	HIGH to LOW	MR to Qn; see Figure 9								
	propagation delay	$V_{CC} = 4.5 V$	-	22	38	-	48	-	57	ns
	uelay	$V_{CC} = 5 \text{ V}; C_{L} = 15 \text{ pF}$	-	19	-	-	-	-	-	ns
		MR to Qn; see Figure 9								
		$V_{CC} = 4.5 V$	-	19	35	-	44	-	53	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	16	-	-	-	-	-	ns
tt	transition time	Qn output; see Figure 7	[2]							
		V _{CC} = 4.5 V	-	7	15	-	19	-	22	ns
t _W	pulse width	CP input; see Figure 7								
		V _{CC} = 4.5 V	20	12	-	25	-	30	-	ns
		MR input LOW; see Figure 9								
		$V_{CC} = 4.5 V$	20	11	-	25	-	30	-	ns
t _{rec}	recovery time	MR to CP; see Figure 9								
	-	V _{CC} = 4.5 V	5	-10	-	5	-	5	-	ns
t _{su}	set-up time	Dn to CP; see Figure 7								
		V _{CC} = 4.5 V	16	5	-	20	-	24	-	ns
t _h	hold time	Dn to CP; see Figure 7								
		V _{CC} = 4.5 V	5	0	-	5	-	5	-	ns
f _{max}	maximum	CP input; see Figure 7								
max	frequency	$V_{CC} = 4.5 V$	25	49	-	20	-	17	-	MHz
		V _{CC} = 5 V; C _L = 15 pF	-	54	-	-	-	-	-	MHz
C _{PD}	power dissipation capacitance		[3] _	34	-	-	-	-	-	pF

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[2] t_t is the same as t_{THL} and t_{TLH} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 f_o = output frequency in MHz;

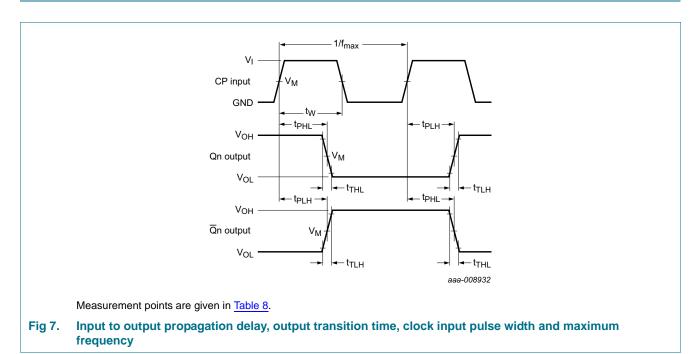
 $\Sigma \ (C_L \times V_{CC}{}^2 \times f_o)$ = sum of outputs;

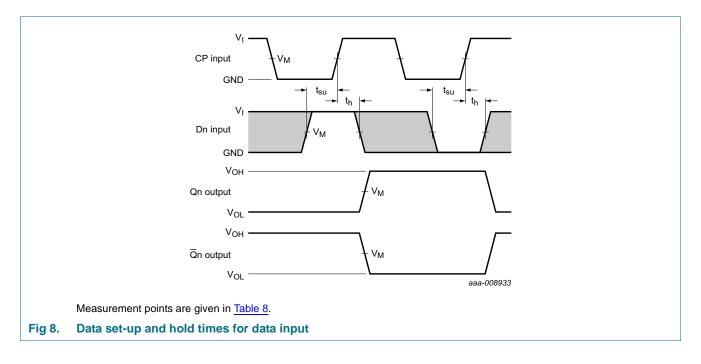
 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V.

Quad D-type flip-flop with reset; positive-edge trigger

11. Waveforms





Quad D-type flip-flop with reset; positive-edge trigger

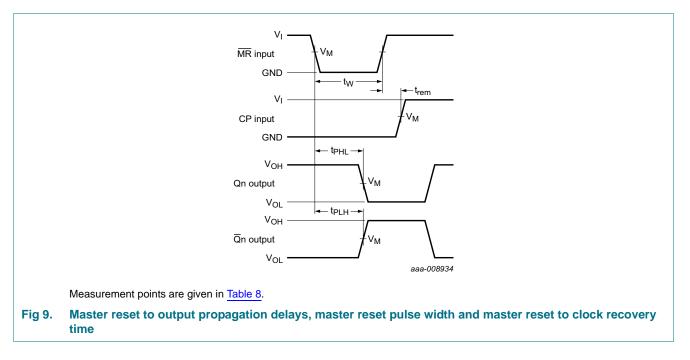


Table 8.Measurement points

Туре	Input		Output
	VI	V _M	V _M
74HC175	V _{CC}	0.5V _{CC}	0.5V _{CC}
74HCT175	3 V	1.3 V	1.3 V

Quad D-type flip-flop with reset; positive-edge trigger

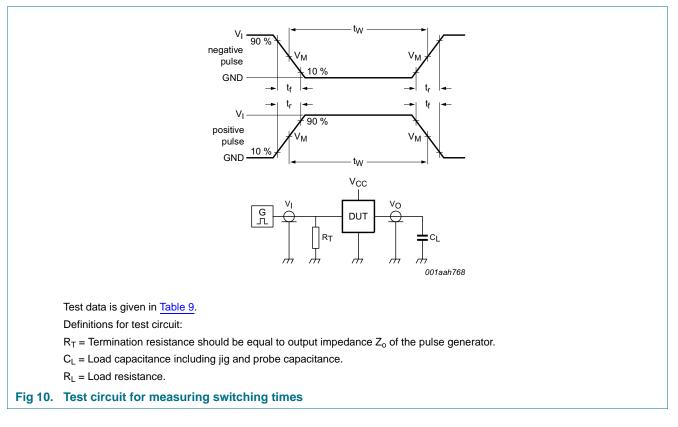


Table 9. Test data

Туре	Input Load			Test	
	VI	t _r , t _f	CL	RL	
74HC175	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	t _{PLH} , t _{PHL}
74HCT175	3 V	6 ns	15 pF, 50 pF	1 kΩ	t _{PLH} , t _{PHL}

Quad D-type flip-flop with reset; positive-edge trigger

12. Package outline

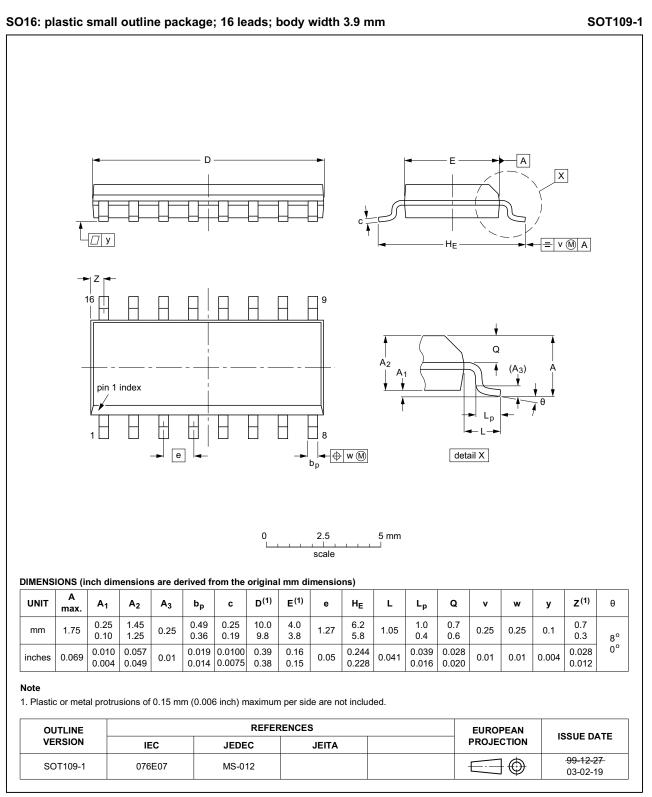


Fig 11. Package outline SOT109-1 (SO16)

74HC_HCT175

Quad D-type flip-flop with reset; positive-edge trigger

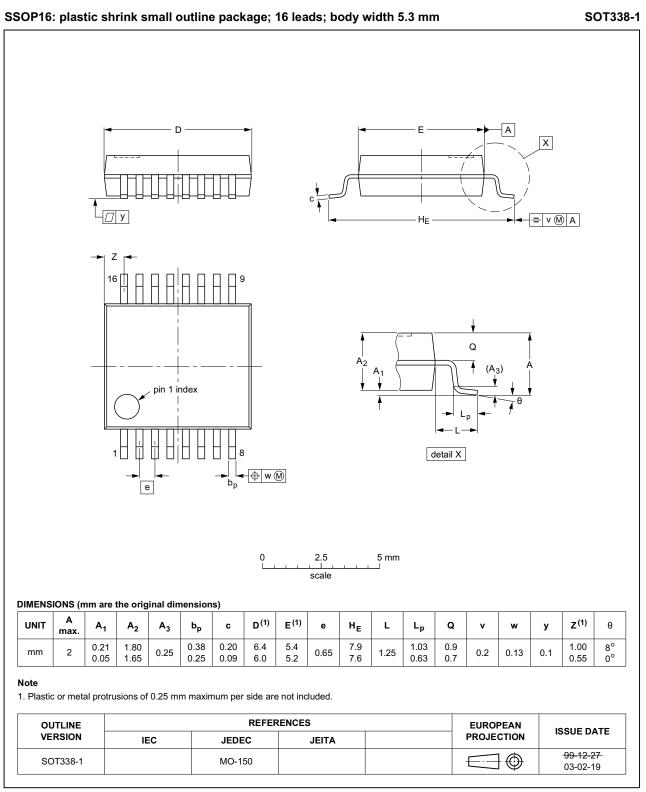


Fig 12. Package outline SOT338-1 (SSOP16)

74HC_HCT175

Quad D-type flip-flop with reset; positive-edge trigger

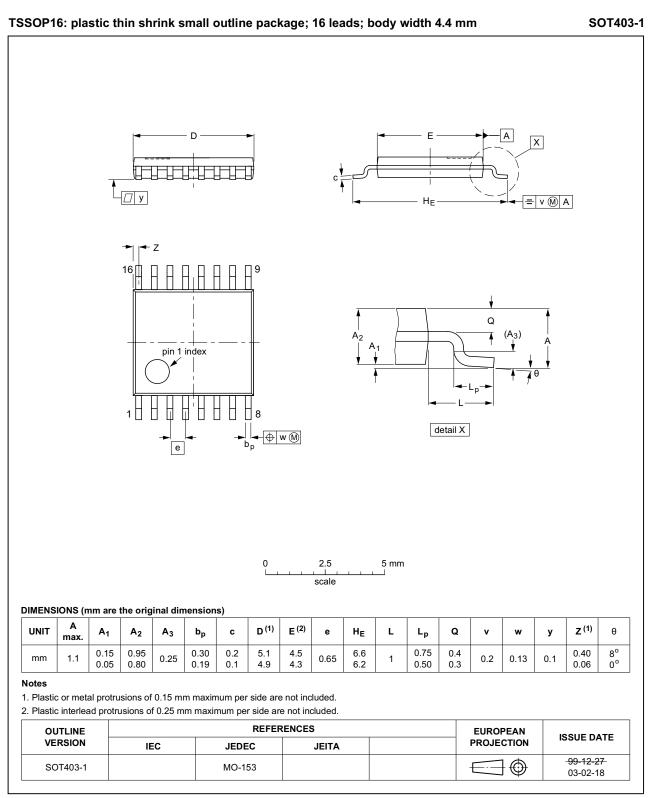


Fig 13. Package outline SOT403-1 (TSSOP16)

74HC_HCT175

13. Abbreviations

Table 10. Abbreviations			
Acronym	Description		
CMOS	Complementary Metal-Oxide Semiconductor		
DUT	Device Under Test		
ESD	ElectroStatic Discharge		
НВМ	Human Body Model		
MM	Machine Model		
TTL	Transistor-Transistor Logic		

14. Revision history

Table 11.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74HC_HCT175 v.5	20160129	Product data sheet	-	74HC_HCT175 v.4	
Modifications:	Type numbers 74HC175N and 74HCT175N (SOT38-4) removed.				
74HC_HCT175 v.4	20140408	Product data sheet	-	74HC_HCT175 v.3	
Modifications:	General description corrected (errata).				
74HC_HCT175 v.3	20140331	Product data sheet	-	74HC_HCT175_CNV_2	
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate. 				
74HC_HCT175_CNV_2	19980708	Product specification	-	-	

Quad D-type flip-flop with reset; positive-edge trigger

15. Legal information

15.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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